Discrete POWER & Signal **Technologies** 

# **MPS6523**

**MPS6523** 

FAIRCHILD

SEMICONDUCTOR TM



# **PNP General Purpose Amplifier**

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 68. See PN200 for characteristics.

#### **Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	25	V
V <sub>CBO</sub>	Collector-Base Voltage	45	V
V <sub>EBO</sub>	Emitter-Base Voltage	4.0	V
I <sub>C</sub>	Collector Current - Continuous	500	mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# Thermal Characteristics

Thermal Characteristics   TA = 25°C unless otherwise noted				
Symbol	Characteristic	Max	Units	
		MPS6523	-	
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C	
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	83.3	°C/W	
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	200	°C/W	

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# PNP General Purpose Amplifier (continued)

MPS6523

Electri	Electrical Characteristics TA = 25°C unless otherwise noted				
Symbol	Parameter	Test Conditions	Min	Max	Units

# OFF CHARACTERISTICS

V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 0.5 \text{ mA}, I_{\rm B} = 0$	25		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{E} = 10 \ \mu A, I_{C} = 0$	4.0		V
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 20 \text{ V}, I_E = 0$ $V_{CB} = 20 \text{ V}, I_E = 0, T_A = 60 ^{\circ}\text{C}$		50 1.0	nA μA

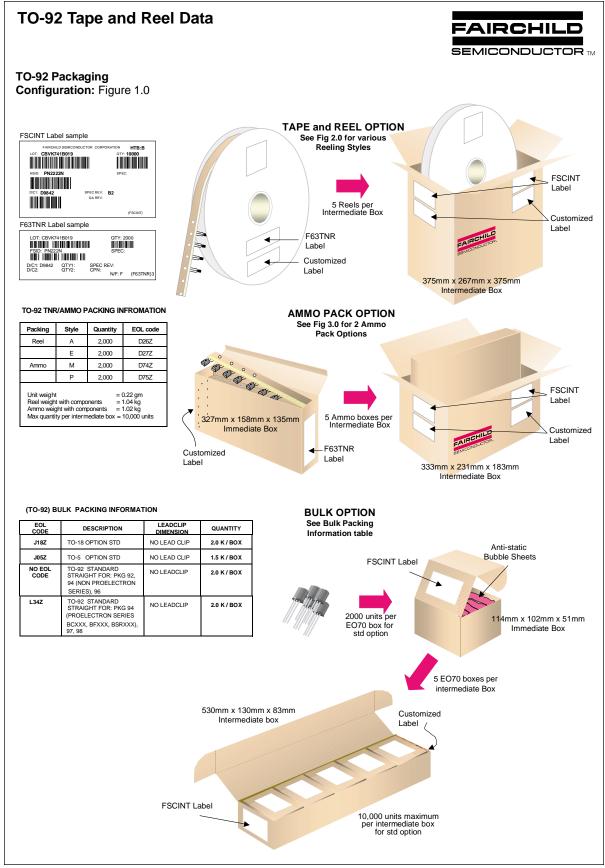
### **ON CHARACTERISTICS\***

h <sub>FE</sub>	DC Current Gain	$V_{CE} = 10 \text{ V}, I_C = 100 \mu\text{A}$ $V_{CE} = 10 V, I_C = 2.0 m\text{A}$	150 300	600	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA}$		0.5	V

# SMALL SIGNAL CHARACTERISTICS

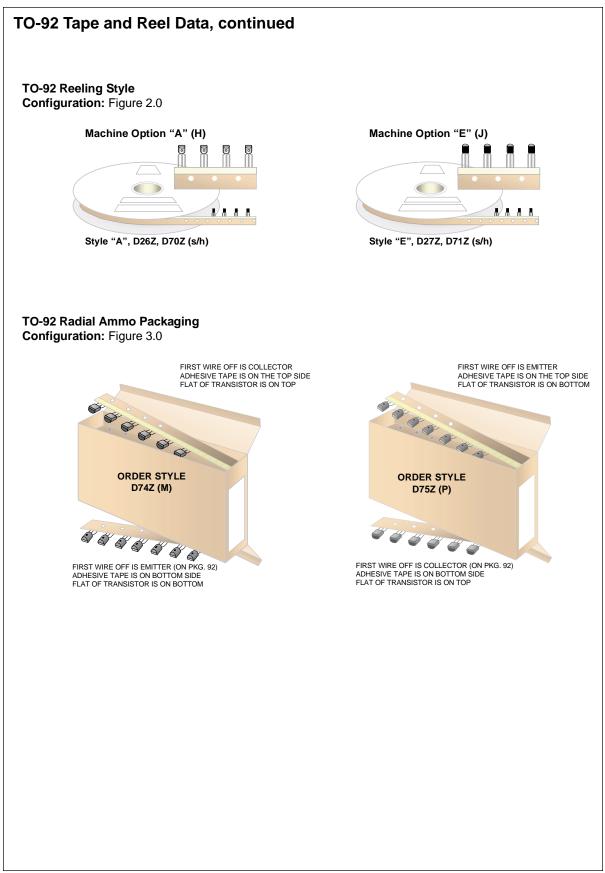
C <sub>ob</sub>	Output Capacitance	$V_{CB} = 10 \text{ V}, \text{ f} = 100 \text{ kHz}$	4.0	pF
NF	Noise Figure		3.0	dB

\*Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

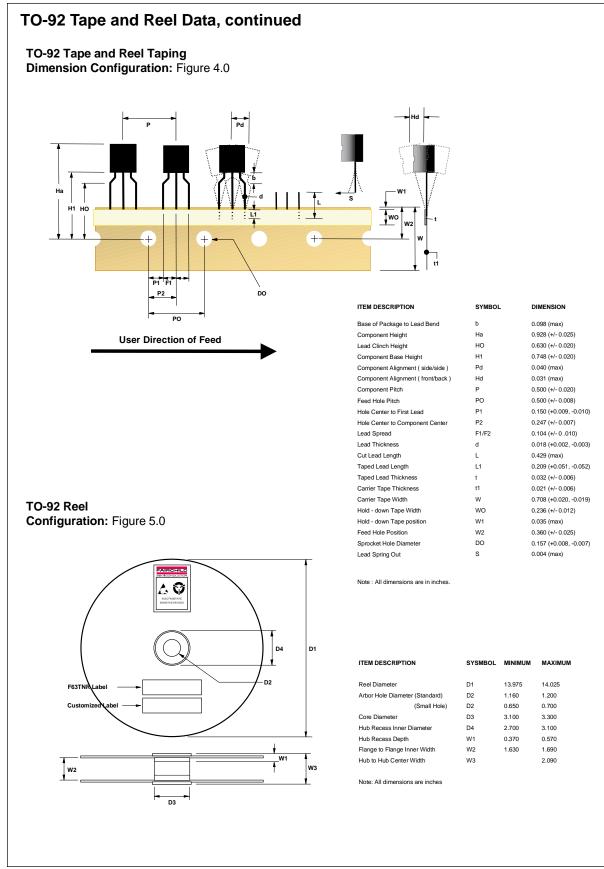


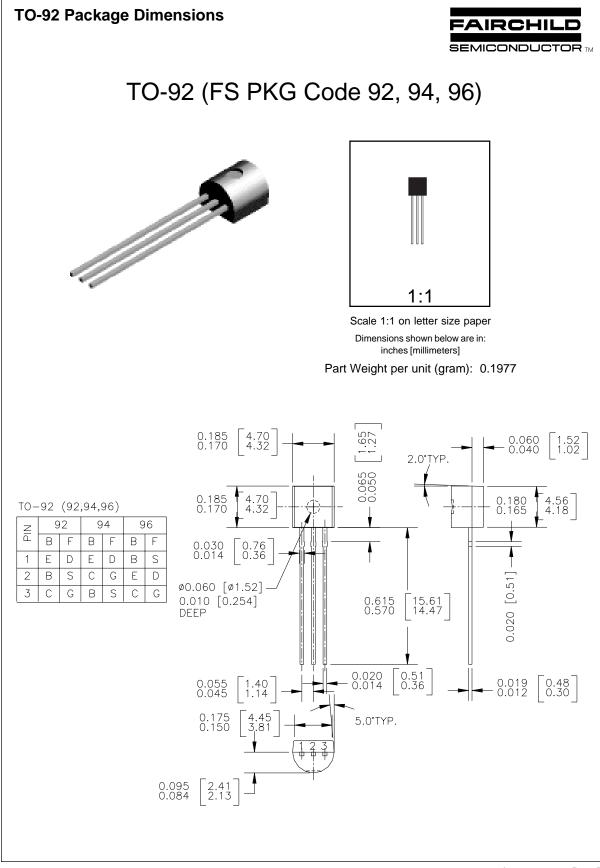
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#### PRODUCT STATUS DEFINITIONS

Definition of Terms

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